

Ratiometric Linear Hall-Effect Sensor

OMH3150, OMH3150S

Obsolete (OMH3150B)



Ceramic Package



Features:

- Ratiometric linear output capable of sinking and sourcing current
- Designed for non-contact switching operations
- Operates over a broad range of supply voltages
- Excellent temperature stability operates in harsh environments
- Suitable for military and space applications
- Processing patterned after class S of MIL-STD-883

Description:

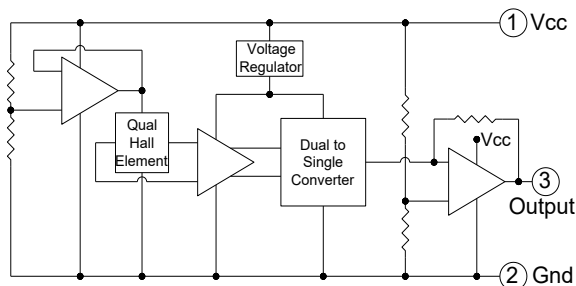
Each ratiometric linear Hall-effect sensor contains a monolithic integrated circuit on a single chip. This circuit incorporates a quadratic Hall sensing element, which minimizes the effects of mechanical and thermal stress on the Hall element and temperature compensating circuitry to compensate for the inherent Hall element sensitivity change over temperature current.

These ratiometric linear Hall-effect sensors provide an output voltage that varies in proportion to the applied magnetic field. The voltage output will increase in response to a south pole (positive) magnetic field applied perpendicular to the package symbolization face, and will decrease in response to a north pole (negative) magnetic field.

These 3150 ratiometric linear Hall-effect sensors can be used as a non-contact sensor for rotary and linear position sensing and for current sensing.

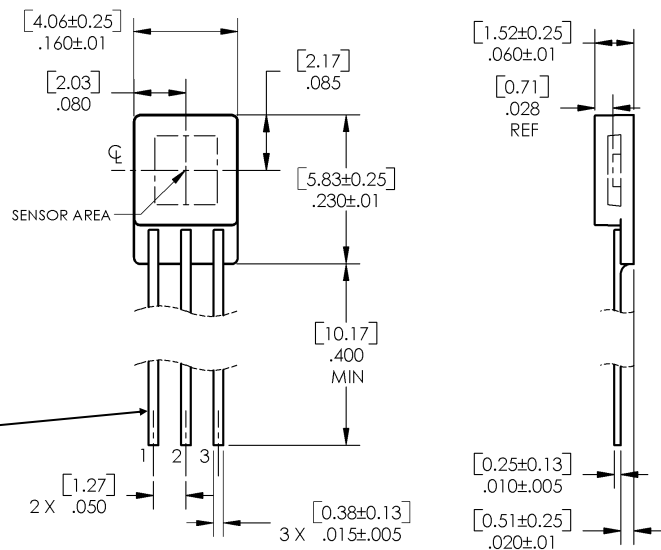
Applications:

- Non-contact magnetic sensing
- Assembly line automation
- Machine automation
- Machine safety
- Door sensor
- Where sensing is required in dirty environments



Lead Information:

Base Material = Kovar
Plating = 80 μ inches Ag over 50-300 μ inches Ni
"S" version only = Solder dip 63 %(SN) - 37 %(pb)



General Note

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Electrical Specifications

Absolute Maximum Ratings

Supply Voltage, V_{CC}	6 V
Storage Temperature Range, T_S	-65° C to +150° C
Operating Temperature Range, T_A	-40° C to +125° C
Lead Soldering Temperature (1/8 inch [3.2 mm] from case for 5 seconds with soldering iron)	260° C ⁽¹⁾
Power Dissipation, P_D	100 mW
Output Current, I_O	5 mA
Magnetic Flux Density, B	Unlimited

Electrical Characteristics (Over Operating Temperature Range at $V_{CC} = 5$ V, unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
V_{CC}	Supply Voltage	4.5	5.0	6.00	V	
I_{CC}	Supply Current 25C -40C 125C	-	5.5 10.0 7.0	10.0 12.0 10.0	mA	$V_{CC} = 6$ V, $I_O = 0$ mA, B = 0G
V_{OQ}	Quiescent Voltage Output	2.25	2.5	2.75	V	B = 0G, $T_A = 25^\circ$ C
		2.10	2.5	2.90	V	B = 0G, $T_A = -40^\circ$ C to +125° C
I_O	Sink Current	0.5	-	-	mA	
I_O	Source Current	-1.0	-	-	mA	

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Electrical Characteristics (Over Operating Temperature Range at $V_{CC} = 5\text{ V}$, unless otherwise noted)

SYMBOL	PARAMETER	OMH3150			UNITS
		MIN	TYP	MAX	
T_A	Operating Temperature Range	-40	-	125	° C
Sens	Sensitivity @ $T_A = 25^\circ\text{C}$	3.00	3.50	4.10	mV/G
$\Delta\text{Sens}(\Delta T)$	Sens Change @ $T_A > 25^\circ\text{C}$ @ $T_A < 25^\circ\text{C}$	-5	-	10	%
		-12	-	3.0	%
$\Delta V_{OQ}(\Delta T)$	V_{OQ} Change over T_A	-	-	± 50	G
$\Delta\text{Sens}(\Delta V)$	Ratiometric Sense Change	-	100	-	%
$\Delta V_{OQ}(\Delta V)$	Ratiometric V_{OQ} Change	-	100	-	%
+Lin	Positive Lin	80	-	105	%
	-40C	90	-	115	
	125C	95	-	115	
-Lin	Negative Lin	80	-	105	%
	-40C	90	-	115	
	125C	95	-	115	
Sym	Output Symmetry	80	100	110	%
	-40C	90	110	120	
	125C	90	110	120	

Note:

- (1) Heat sink leads during hand soldering.
- (2) Negative current is defined as coming out of (sourcing) the output.

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Characteristics Definitions

Quiescent voltage Output: With no magnetic field present the device in the quiescent state and the voltage output is approximately equal to one-half the supply voltage ($V_{OQ} = V_{CC} / 2$) over the operating voltage and temperature range. The change in quiescent voltage output over temperature gives the device's equivalent accuracy and is specified in gauss by the calculation.

$$\Delta V_{OQ(T)} = \frac{V_{OQ(TA)} - V_{OQ(25^{\circ}C)}}{Sens_{(25^{\circ}C)}}$$

Sensitivity: A magnetic south pole at, and perpendicular to, the device's symbolized package face will increase the voltage output above the quiescent value. Conversely a magnetic north pole will decrease the voltage output below the quiescent value. This change in voltage output with applied magnetic field is sensitivity and is specified in mV/G by the calculation.

$$Sens = \frac{V_{O(+500G)} - V_{O(-500G)}}{1000}$$

The change in sensitivity over temperature is specified in percent by the calculation.

$$\Delta Sens_{(\Delta T)} = \frac{Sens_{(TA)} - Sens_{(25^{\circ}C)}}{Sens_{(25^{\circ}C)}} \times 100\%$$

Ratiometry: The quiescent voltage output and sensitivity of these ratiometric linear Hall-effect devices are proportional to the supply voltage. The change in quiescent voltage output with supply voltage is specified in percent by the calculation.

$$\Delta V_{OQ(\Delta V)} = \frac{V_{O(VCC)} - V_{O(5V)}}{V_{CC} / 5V} \times 100\%$$

This change in sensitivity with supply voltage is also specified in percent by the calculation.

$$\Delta Sens_{(\Delta V)} = \frac{V_{OQ(VCC)} / V_{OQ(5V)}}{V_{CC} / 5V} \times 100\%$$

Linearity & Symmetry: The ability of the voltage output to vary in constant proportion to the applied magnetic field is linearity and is specified in percent by the calculation.

$$+ \text{ Linearity} = \frac{V_{O(+500G)} - V_{OQ}}{2(V_{O(250G)} - V_{OQ})} \times 100\%$$

$$- \text{ Linearity} = \frac{V_{O(-500G)} - V_{OQ}}{2(V_{O(-250G)} - V_{OQ})} \times 100\%$$

The output is also specified in percent by the calculation.

$$- \text{ SYM} = \frac{V_{O(500G)} - V_{OQ}}{V_{OQ} - V_{O(-500G)}} \times 100\%$$

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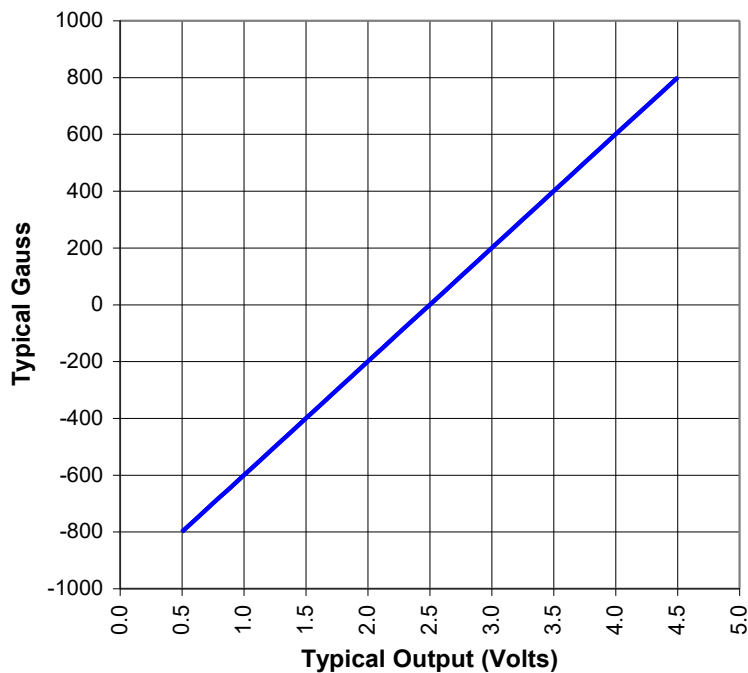
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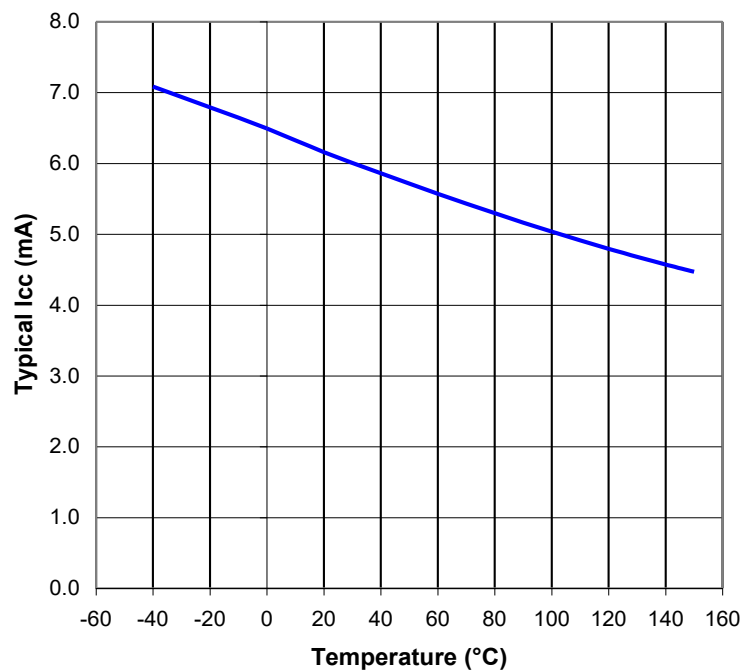
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Output vs Gauss



Icc vs Temperature



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